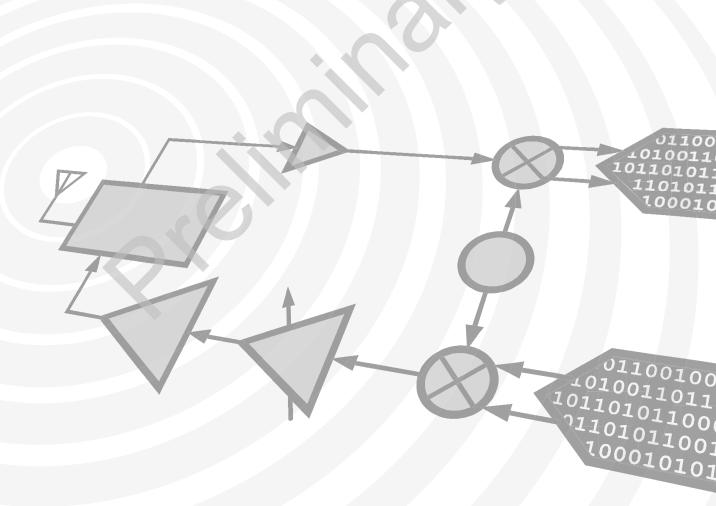




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## HMC985ALP4KE

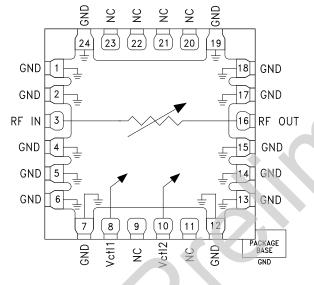
## GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

#### **Typical Applications**

The HMC985ALP4KE is ideal for:

- Point-to-Point Radio
- VSAT Radio
- Test Instrumentation
- Microwave Sensors
- Military, ECM & Radar

#### **Functional Diagram**



#### Features

Wide Bandwidth: 10 - 40 GHz Excellent Linearity: +32 dB Input IP3 Wide Attenuation Range: 35 dB No External Matching

24 Lead 4x4 mm SMT Package: 16 mm<sup>2</sup>

#### General Description

The HMC985ALP4KE is an absorptive Voltage Variable Attenuator (VVA) which operates from 10 - 40 GHz and is ideal in designs where an analog DC control signal must be used to control RF signal levels over a 35 dB dynamic range. It features two shunt-type attenuators which are controlled by two analog voltages, Vctl1 and Vctl2. Optimum linearity performance of the attenuator is achieved by first varying Vctl1 of the first attenuation stage from -3V to 0V with Vctl2 fixed at -3V. The control voltage of the second attenuation stage, Vctl2, should then be varied from -3V to 0V with Vctl1 fixed at 0V.

If the Vctl1 and Vctl2 pins are connected together it is possible to achieve the full analog attenuation range with only a small degradation in input IP3 performance. Applications include AGC circuits and temperature compensation of multiple gain stages in microwave point-to-point and VSAT radios.

#### Electrical Specifications, $T_A = +25$ °C, Test Condition Vctl1 = Vctl2

Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss <sup>[1]</sup>	10 - 20 GHz		3	3.5	dB
	20 - 30 GHz		3	4	dB
	30 -40 GHz		3.5	4.5	dB
Attenuation Range	10 - 20 GHz	25	30		dB
	20 - 30 GHz	30	35		dB
	30 - 40 GHz	35	40		dB
Input Return Loss	10 - 40 GHz		13		dB
Output Return Loss	10 - 40 GHz		13		dB
Input Third Order Intercept (two-tone input Power = 10 dBm Each Tone) <sup>[2]</sup>			33		dBm

[1] Vcntl1 = Vcntl2 =-2.4V

[2] Vcntl1 = Vcntl2 =-2.0V worst case

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### GaAs MMIC VOLTAGE - VARIABLE ATTENUATOR, 10 - 40 GHz

#### Absolute Maximum Ratings

Control Voltage	+1 to -5V	
Input RF Power	30 dBm	
Maximum Junction Temperature	165 °C	
Thermal Resistance (R <sub>TH</sub> ) (junction to ground paddle)	62 °C/W	
Operating Temperature	-40°C to +85°C	
Storage Temperature	-65°C to 125°C	
ESD Sensitivity (HBM)	Class1A, passed 250V	



#### **Outline Drawing**

